Features
- 26 dB Small Signal Gain
- 39 dBm Third Order Intercept Point (OIP3)
- Integrated Power Detector
- Lead-Free 4 mm 24-lead QFN Package
- 100% RF Testing
- RoHS* Compliant and 260°C Reflow Compatible

Description
The XP1035-QH is a packaged linear power amplifier that operates over the 5.9-9.5 GHz frequency band. The device provides 26 dB gain and 39 dBm Output Third Order Intercept Point (OIP3) across the band and is offered in an industry standard, fully molded 4x4mm QFN package. The packaged amplifier is comprised of a three stage power amplifier with an integrated, temperature compensated on-chip power detector. The device includes on-chip ESD protection structures and DC by-pass capacitors to ease the implementation and volume assembly of the packaged part. The device is manufactured in GaAs PHEMT device technology with BCB wafer coating to enhance ruggedness and repeatability of performance. The XP1035-QH is specifically designed for PtP radio applications and is well suited for other telecom applications such as SATCOM and VSAT.

Ordering Information
<table>
<thead>
<tr>
<th>Part Number</th>
<th>Package</th>
</tr>
</thead>
<tbody>
<tr>
<td>XP1035-QH-0G00</td>
<td>bulk quantity</td>
</tr>
<tr>
<td>XP1035-QH-0G0T</td>
<td>tape and reel</td>
</tr>
<tr>
<td>XP1035-QH-EV1</td>
<td>evaluation module</td>
</tr>
</tbody>
</table>

1. Reference Application Note M513 for reel size information.

### Electrical Specifications: 5.9 - 9.5 GHz (Ambient Temperature T = 25°C)

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Units</th>
<th>Min.</th>
<th>Typ.</th>
<th>Max.</th>
</tr>
</thead>
<tbody>
<tr>
<td>Small Signal Gain (S21)</td>
<td>dB</td>
<td>-</td>
<td>26</td>
<td>-</td>
</tr>
<tr>
<td>Input Return Loss (S11)</td>
<td>dB</td>
<td>-</td>
<td>13</td>
<td>-</td>
</tr>
<tr>
<td>Output Return Loss (S22)</td>
<td>dB</td>
<td>-</td>
<td>10</td>
<td>-</td>
</tr>
<tr>
<td>Reverse Isolation (S12)</td>
<td>dB</td>
<td>-</td>
<td>45</td>
<td>-</td>
</tr>
<tr>
<td>Psat</td>
<td>dBm</td>
<td>-</td>
<td>29</td>
<td>-</td>
</tr>
<tr>
<td>P1dB</td>
<td>dBm</td>
<td>-</td>
<td>27.5</td>
<td>-</td>
</tr>
<tr>
<td>OIP3</td>
<td>dBm</td>
<td>-</td>
<td>39</td>
<td>-</td>
</tr>
<tr>
<td>Drain Bias Voltage (Vd1,2,3)</td>
<td>VDC</td>
<td>-</td>
<td>6</td>
<td>-</td>
</tr>
<tr>
<td>Detector Bias Voltage (Vdet,ref)</td>
<td>VDC</td>
<td>-</td>
<td>5</td>
<td>-</td>
</tr>
<tr>
<td>Gate Bias Voltage (Vg1,2,3)</td>
<td>VDC</td>
<td>-2</td>
<td>-1</td>
<td>-</td>
</tr>
<tr>
<td>Supply Current (Id1)</td>
<td>mA</td>
<td>-</td>
<td>70</td>
<td>-</td>
</tr>
<tr>
<td>Supply Current (Id2)</td>
<td>mA</td>
<td>-</td>
<td>140</td>
<td>-</td>
</tr>
<tr>
<td>Supply Current (Id3)</td>
<td>mA</td>
<td>-</td>
<td>280</td>
<td>-</td>
</tr>
</tbody>
</table>

### Absolute Maximum Ratings

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Absolute Max.</th>
</tr>
</thead>
<tbody>
<tr>
<td>Supply Voltage (Vd1,2,3)</td>
<td>+7.2 V</td>
</tr>
<tr>
<td>Supply Current (Id1,2,3)</td>
<td>600 mA</td>
</tr>
<tr>
<td>Gate Bias Voltage (Vg1,2,3)</td>
<td>-3 V</td>
</tr>
<tr>
<td>Max Power Dissipation (Pdiss)</td>
<td>4.2 W</td>
</tr>
<tr>
<td>RF Input Power</td>
<td>+15 dBm</td>
</tr>
<tr>
<td>Operating Temperature (Ta)</td>
<td>-55°C to +85°C</td>
</tr>
<tr>
<td>Storage Temperature (Tstg)</td>
<td>-65°C to +165°C</td>
</tr>
<tr>
<td>Channel Temperature (Tch)²</td>
<td>150°C</td>
</tr>
<tr>
<td>MSL Level (MSL)</td>
<td>MSL3</td>
</tr>
</tbody>
</table>

3. Operation of this device above any one of these parameters may cause permanent damage.

4. Channel temperature directly affects a device’s MTTF. Channel temperature should be kept as low as possible to maximize lifetime.

### Recommended Layout

![Recommended Layout Diagram](image)

Recommended Decoupling Capacitors: 100pF 0402, 10µF 0805
Typical Performance Curves

**XP1035-QH: $S_{11}$ (dB) at $V_d=6V$, $I_d=500mA**

-30.0 -25.0 -20.0 -15.0 -10.0 -5.0 0.0 5.0 10.0 15.0 20.0 25.0 30.0 35.0
RF Frequency (GHz)

**XP1035-QH: $S_{21}$ (dB) at $V_d=6V$, $I_d=500mA**

-30.0 -25.0 -20.0 -15.0 -10.0 -5.0 0.0 5.0 10.0 15.0 20.0 25.0 30.0 35.0
RF Frequency (GHz)

**XP1035-QH: $S_{22}$ (dB) at $V_d=6V$, $I_d=500mA**

-30.0 -25.0 -20.0 -15.0 -10.0 -5.0 0.0 5.0 10.0 15.0 20.0 25.0 30.0 35.0
RF Frequency (GHz)

**XP1035-QH: $S_{12}$ (dB) at $V_d=6V$, $I_d=500mA**

-60.0 -50.0 -40.0 -30.0 -20.0 -10.0 0.0 10.0 20.0 30.0 40.0 50.0 60.0
RF Frequency (GHz)

**XP1035-QH: OIP3 (dBm) at $V_d=6V$, $I_d=500mA**

20.0 25.0 30.0 35.0 40.0 45.0
RF Frequency (GHz)

**XP1035-QH: Psat (dBm) at $I_d=500mA$, $V_d=6V**

0.0 5.0 10.0 15.0 20.0 25.0 30.0 35.0
RF Frequency (GHz)
XP1035-QH

Power Amplifier
5.9 - 9.5 GHz

Rev. V2

Typical Performance Curves (cont.)

XP1035-QH: Pout (dBm) and Gain (dB) vs Pin (dBm)
Id=500mA, Vd=6V, +25 C

XP1035-QH: C/13 vs Pout at Id=500mA, Vd=6V, +25 C, 10 MHz Span

XP1035-QH: P1dB (dBm) at Id=500mA, Vd=6V

XP1035-QH: Detector (mV) vs Pout (dBm) at Id=500mA, Vd=6V, -40 C

XP1035-QH: Detector (mV) vs Pout (dBm) at Id=500mA, Vd=6V, +80 C

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MTTF

XP1035-QH-0G00: MTTF (hours) vs. Package Base Temperature
Vdd = 6.0 V, Id = 500 mA

XP1035-QH-0G00: Tth vs. Package Base Temperature
Vdd = 6.0 V, Id = 500 mA

XP1035-QH-0G00: Rth vs. Package Base Temperature
Vdd = 6.0 V, Id = 500 mA
**App Note [1] Biasing** - As shown in the Pin Designations table, the device is operated by biasing VD1,2,3 at 5.0V with 70, 140, 280mA respectively. It is recommended to use active bias to keep the currents constant in order to maintain the best performance over temperature. Depending on the supply voltage available and the power dissipation constraints, the bias circuit may be a single transistor or a low power operational amplifier, with a low value resistor in series with the drain supply used to sense the current. The gate of the pHEMT is controlled to maintain correct drain current and thus drain voltage. The typical gate voltage needed to do this is -1.0V. Make sure to sequence the applied voltage to ensure negative gate bias is available before applying the positive drain supply.

**App Note [2] Board Layout** - As shown in the board layout, it is recommended to provide 100pF decoupling caps as close to the bias pins as possible, with additional 10μF decoupling caps.
Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.
Power Amplifier
5.9 - 9.5 GHz

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